## PATENT APPLICATION

# HIGH GAIN WIDEBAND DRIVER AMPLIFIER

Inventor(s): Andrea Betti-Berutto, a citizen of Italy, residing at

294 Waverley St., Apt. 6 Menlo Park, CA 94025

Stefano D'Agostino, a citizen of Italy, residing at

1002 Roble Ave.

Menlo Park, CA 94025

Assignee: iTerra Communications, LLC

1585 Reliance Way Fremont, CA 94539

Entity: Small

5

## HIGH GAIN WIDEBAND DRIVER AMPLIFIER

#### BACKGROUND OF THE INVENTION

[01]The present invention relates in general to high speed integrated circuitry, and in particular to methods and circuitry for implementing high gain driver amplifiers having very large bandwidth of the type used in optical communication systems.

[02] The coming of the modern information age has brought about phenomenal growth in demand for telecommunications-based services and products, driven primarily by the Internet. As the burgeoning expansion of the Internet continues along an unprecedented and unpredictable path, many new applications are foreseen and expected. These applications are placing increasing demands for ultrahigh speed circuit solutions that maximize integration while minimizing power consumption among other requirements. In parallel, driven by the explosive growth in bandwidth requirements of multimedia applications, various ultra-high bit rate transmission techniques have been developed. Fiber-optic communications system speeds have increased from asynchronous-transfer-mode (ATM) rates of 155 Mb/s and synchronous optical network (SONET) rates of 622 Mb/s to the optical carrier (OC) standard of OC-192 at 10 Gb/s and OC-768 at 40 Gb/s.

10th 703] Recent advances in optical and semiconductor processing technologies are enabling 40 Gb/s systems to move from research laboratories to production ready systems that can be manufactured in large volumes. However, the design of various functional blocks, especially at the interface with the fiber, remains a challenging task. For example, one of the most critical circuits in an optical transmitter is the amplifier in the optical modulator that drives the fiber. At the 40 Gb/s rate, the amplifier must exhibit very large bandwidth. It is also required to drive a relatively large (e.g., 7Vpp – or is it 2.5Vpp?) signal. The large bandwidth requires smaller and faster transistors while the higher voltage operation requires the opposite. The driver amplifier is also

Cathola,

required to perform a limiting function to achieve a stable eye diagram at its output.

These various and competing requirements create a set of tradeoffs that make the task of designing the amplifier a particularly difficult one.

pu do

10

m

15

20

25

Current approaches to designing the driver amplifier are based on a distributed amplifier architecture. This type of an amplifiery connects a number of parallel amplifier cells that are typically made up of a single transistor or a cascoded pair of transistors. The limiting function is achieved by making the amplifier working in deep saturation. The power compression in this design, however, causes about 3-4 dB of gain loss, requiring more cells to achieve the desired overall gain or several cascaded devices. A larger number of amplifier cells, however, results in lower bandwidth and increased power consumption. An alternative approach separates the limiting function from the amplifier by using a limiter circuit that drives one or more distributed amplifiers such that the amplifier need not operate in saturation region. There are drawbacks to this approach as well. At 40Gb/s most of the circuitry is implemented in a single-ended architecture and as such the addition of a single-ended limiter reduces the overall achievable gain, while the power levels remain as another constraint.

[05] An improvement has been offered by an implementation that combines two distributed amplifiers in parallel to obtain an additional 3dB of voltage gain and a higher output voltage. The combined amplifier thus includes two input gate lines and a common high current drain line. To drive the two input gate lines, a divider (or splitter) preamplifier is used which receives the single-ended output of the limiter and produces two output signals that drive the two input gate lines of the final amplifier which is commonly referred to as the combiner amplifier. While this approach has provided improvements in the power versus bandwidth tradeoff, it has added more circuitry and still requires a single-ended limiter. Additionally, this solution requires a large DC level shift (from about 8V down to near 0V) between the output of the divider preamplifier and the combiner amplifier. This level shift typically requires

25

5

large passive elements such as resistors or capacitors that are too large to be integrated on the same chip as the amplifier and add to the power consumption of the device.

[06] There is therefore a need for improved methods and circuitry for implementing high gain wideband amplifiers.

#### **BRIEF SUMMARY OF THE INVENTION**

[07] The present invention provides methods and circuitry for implementing monolithic high gain wideband amplifiers. Broadly, the invention implements an amplifier with a limiter that also performs the divider function. In a specific embodiment, the limiter is designed to make available two in-phase outputs that are then used to drive the two gate input lines of a combiner distributed amplifier. The resulting amplifier essentially eliminates the divider distributed preamplifier of the prior art while achieving the desired bandwidth, gain and power. The limiter/divider of the invention also reduces the level shifting task to small enough levels to eliminate the need for large capacitors or resistors allowing a higher level of integration.

amplifier circuit including a limiter preamplifier having a differential amplifier coupled to receive a differential signal at its inputs and configured to generate a differential output signal made up of a first output signal and a second output signal, and an output stage having a first differential output amplifier coupled to the first output signal and a second differential output amplifier coupled to the second output signal; and a combiner distributed amplifier having a first input coupled to an output of the first differential output amplifier, and a second input coupled to an output of the second differential output amplifier, wherein the output of the first differential output amplifier and the output of the second differential output amplifier are of the same phase.

5

- [09] In another embodiment, the present invention provides a method of amplifying a high frequency signal including receiving a differential signal at differential inputs of a limiter circuit; performing a limiting function on the differential signal; using the limiter circuit to generate a pair of in-phase output signals; and applying, respectively, the pair of in-phase output signals to a pair of input terminals of a combiner distributed amplifier.
- In yet another embodiment, the present invention provides a limiter amplifier having a differential amplifier cell coupled to receive a differential signal at its inputs and configured to generate a differential output signal made up of a first signal and a second signal; and an output stage having a first differential output amplifier coupled to the first signal and a second differential output amplifier coupled to the second signal, wherein the first differential output amplifier is configured to generate a first single-ended output signal and the second differential output amplifier is configured to generate a second single-ended output signal that is in phase with the first single-ended output signal.
- [11] The following detailed description and the accompanying drawings will provide a better understanding of the nature and advantages of the driver amplifier of the present invention.

#### **BRIEF DESCRIPTION OF THE DRAWINGS**

- [12] Figure 1 is a simplified block diagram of a wideband amplifier according to one embodiment of the present invention;
- [13] Figure 2 is a block diagram of limiter/divider preamplifier according to an exemplary embodiment of the present invention;
  - [14] Figure 3 is a partial schematic of an exemplary circuit implementation for the limiter/divider preamplifier of the present invention;

- [15] Figures 4A and 4B show exemplary distributed combiner amplifiers for use in the wideband driver amplifier of the present invention; and
- [16] Figure 5 is a block diagram of a high frequency data communication system employing the wideband driver amplifier according to the present invention.

15

20

25

[17] In the various figures, the same reference numerals are used to designate the same elements.

## DETAILED DESCRIPTION OF THE INVENTION

- One embodiment of the invention is shown in Figure 1. Amplifier 100 includes a preamplifier 102 that receives a differential input signal Vin at its inputs IN1 and IN2. Preamplifier 102 acts as a limiter as well as a divider to produce a pair of limited output signals Vo1 and Vo2 that are in phase with respect to each other. Signals Vo1 and Vo2 are respectively applied to two input gate lines 106 and 108 of a combiner distributed amplifier 104. The output OUT of combiner distributed amplifier 104 provides the final output of amplifier 100. Distributed amplifier 104 is shown as having five amplifier cells 110 in each of its halves. It is to be understood, however, this is for illustrative purposes only that the number of amplifier cells varies depending on the desired gain and other requirements of a given application. Implementations for distributed amplifier 104 will be described further below in greater detail in connection with Figures 4A and 4B.
- [19] Unlike prior art implementations that require a limiter amplifier that would then be followed by a divider (or splitter) distributed amplifier, the present invention has developed a circuit technique that allows for combining the signal limiting and the signal splitting functions into one circuit, preamplifier 102. Referring to Figure 2, there is shown a block diagram of an exemplary implementation for

20

25

30

•

5

preamplifier 102. This embodiment includes a number of differential limiting amplifiers 200, in this example three, that are serially connected as shown. The number of differential amplifiers 200 depends on the desired gain as well as the process technology among other factors. The differential output of the final amplifier 200-3 includes a pair of signals V(0) and V(180) that are 180 degrees out of phase with respect to each other. Signals V(0) and V(180) are respectively applied to an input of differential amplifiers 202-1 and 202-2. By tapping the appropriate output leg of the differential output of each of amplifiers 202-1 and 202-2, two signals that are in phase with respect to each other are provided at nodes 203-1 and 203-2. The splitting of the signal is thus achieved using the limiting amplifiers. The in-phase signals on nodes 203-1 and 203-2 are then level shifted by level shift circuits 204-1 and 204-2, respectively, to generate output signal Vo1 and Vo2 that drive the inputs of combiner distributed amplifier 104.

[20] Figure 3 shows an exemplary circuit implementation for a section of preamplifier 102 including differential limiter amplifier 200-3 and amplifiers 202-1 and 202-2. Differential limiting amplifier 200-3 includes a differential pair input stage 300 that is followed by a level shifting buffer 302. Differential pair input stage 300 includes input transistors M1 and M2 that are coupled to the positive power supply VDD1 through respective series RL loads, and a current source transistor M3 that connects the common-source node of the pair to the negative power supply VSS1. Differential pair input stage 300 provides the desired gain for amplifier 200-3. The outputs of gain stage 300 are connected to buffer 302. Buffer 302 includes sourcefollower transistors M4 and M5, each of which has a series of diodes (D1, D2, D3 for M4 and D4, D5, D6 for M5) connected at its source. The diodes are coupled to level shifted negative power supply VSS LS as shown. Buffer 302 provides level shifting and impedance transformation to optimize the interface with the next stage. The 180 degrees out of phase outputs V(0) and V(180) of buffer 302 each respectively connects to one input of a differential pair amplifiers 202-1 and 202-2. The other inputs of amplifiers 202-1 and 202-2 are resistively terminated by resistors R1 and R2, respectively. These resistors may have values of, for example, 50 ohms. Differential

25

5

amplifiers 202-1 and 202-2 are similar in their construction to differential amplifier 300, except that they operate with level shifted supply voltages VDD2 and VSS2. To obtain a pair of in-phase signals, the non-inverting output (node 303) of differential pair 202-1 is tapped as its output, while the inverting output (node 305) of differential pair 202-2 is tapped as its output. The pair of in-phase output signals Vol'(0) and Vo2'(0) are level shifted before being applied to combiner distributed amplifier 104.

- [21] It is to be understood that the specific transistor level implementation shown in Figure 3 is simplified and is for illustrative purposes only. Other variations and modification are possible. For example, the symbols used for the transistors indicate a process that uses GaAs field effect transistor technology. However, the invention is not limited to a specific process technology, and other technologies including, for example, AlGaAs/InGaAs high electron mobility transistor (HEMT), SiGe, silicon bipolar, InP or AlGaAs/GaAs heterojunction bipolar transistor (HBT) technologies and the like may also be used to implement the circuitry. Also, diodes D1 through D6 may be implemented in various ways including, for example, transistors operating as diodes. In another variation, the RL load for the untapped output leg in each of differential pairs 202-1 and 202-2, may be removed such that the drain terminals of transistors M8 and M12 connect to VDD2 directly. This results in a smaller amplifier cell and eliminates the miller capacitance effect which improves the bandwidth of the amplifier. Furthermore, to obtain in-phase output signals, the outputs Vo1'(0) and Vo2'(0) need not necessarily be tapped directly off of an output branch of its respective differential pair. Alternative embodiments may include other inverting buffers coupled to the outputs of differential pairs 202-1 or 202-2.
- [22] By thus combining the limiting and signal splitting functions into one circuit, the invention eliminates the need for separate limiter and divider circuitry. This results in a number of advantages. One advantage is the significant reduction in circuit overhead and power consumption. Another advantage is the reduction in the amount of required DC level shifting that needs to occur before applying the signal to the combiner distributed amplifier. In one application, the signal at the input of the

25

5

, , •

combiner distributed amplifier is required to be around 0V. The prior art divider distributed amplifier required a signal as large as, for example, 8V. The interface between the divider distributed amplifier and the combiner distributed amplifier, therefore, required a relatively large DC level shift (8V to 0V). This necessitated the use of large passive elements such as capacitors or resistors to achieve the shift in the DC voltage level. The limiter/divider preamplifier of the present invention, on the other hand, operates with a signal in the range of, for example, 2V. This makes the task of DC level shifting much easier allowing, for example, a few diodes to achieve the desired level shift. Referring back to Figure 2, level shift blocks 204-1 and 204-2 may thus be implemented by a number, for example three, serially-connected diodes, similar to diodes D1, D2 and D3 (or D4, D5 and D6) in Figure 3.

- [23] Figures 4A and 4B show exemplary combiner distributed amplifiers 400A and 400B for use in the wideband driver amplifier of the present invention. Distributed combiner amplifier 400A uses common-source single-transistor amplifier cells 402 while distributed combiner amplifier 400B uses amplifier cells 404 each of which is made up of a pair of cascoded transistors. The cascoded amplifier cell enlarges the overall size but increases the bandwidth of the distributed amplifier. The in-phase signals IN1 and IN2 drive the gate terminals of amplifier cells in the top half and the bottom half of the combiner distributed amplifier, respectively. It is to be understood that the two simplified implementations for the combiner distributed amplifier are provided for illustrative purposes only, and that other variations and modifications are possible.
- In another embodiment, the present invention provides an ultra-high bit rate communication system enabled by the wideband amplifier of the type shown in Figure 1. Figure 5 is a block diagram of the transmitter/receiver section 500 of a fiber optic communication system implementing, for example, the OC-192 (10 Gb/s) or the OC-768 (40 Gb/s) standards. At the receive side, a photo diode 502 receives the optical signal and converts it into an electrical signal. A trans-impedance amplifier TA 504 amplifies the receive signal and applies it to a limiter (or decision circuit) 506.

20

25

5

Limiter 506 supplies its differential output to a demultiplexing circuit DEMUX 508. A clock recovery (CR) circuit 520 extracts a clock signal from the receive signal and supplies it to various blocks in transmitter/receiver 500. DEMUX 508 performs a serial to parallel conversion that converts a serial receive signal having a high frequency, e.g., 40Gb/s, to multiple (e.g., 16) parallel lower frequency signals at, e.g., 2.5Gb/s. The lower frequency signal is then supplied to a digital signal processing block DSP 510 for further processing. On the transmit side, a multiplexing circuit MUX 512 receives a multiple parallel lower frequency transmit signals at its input and converts them into a serial differential signal having higher frequency. A driver amplifier 514 amplifies the high frequency signal and applies it to an optical modulator 516. Optical modulator 516 in combination with a photo diode 518 converts the electrical signal to a modulated optical signal to be launched into the fiber link. Driver amplifier 514 is a wideband high gain amplifier of the type described above. It is to be understood that the block diagram shown in Figure 5 is simplified and is for illustrative purposes. The transmitter/receiver may include other circuitry performing other functions such as filtering, automatic gain control, and the like.

[25] In conclusion, the present invention provides methods and circuitry for implementing monolithic high gain wideband amplifiers. The wideband amplifier includes a limiter that also performs a signal splitting function to drive a combiner (i.e., double) distributed amplifier. In a specific embodiment, the limiter is designed to make available two in-phase outputs that are then used to drive the two gate input lines of the combiner distributed amplifier. While the above provides detailed description of specific embodiments, it is to be understood that various alternatives, equivalents and modifications are possible. Therefore, the scope of the invention should not be limited to the embodiments described, and should instead be determined by the following claims and their full breadth of equivalents.